UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.usplo.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/735,989	12/15/2003	Somenath Mitra .	436/12	4147
	7590 10/04/200 MAN GIBSON & DEF	EXAMINER		
900 ROUTE 9 NORTH			ROBINSON, DANIEL LEON	
WOODBRIDG	WOODBRIDGE, NJ 07095		ART UNIT	PAPER NUMBER
			3742	
			<u></u> :	•
			MAIL DATE	DELIVERY MODE
			10/04/2007	PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

		•			
,	Application No.	Applicant(s)			
	10/735,989	MITRA ET AL.			
Office Action Summary	Examiner	Art Unit			
	Daniel L. Robinson	3742			
The MAILING DATE of this communication appeariod for Reply	pears on the cover sheet with the c	correspondence address			
A SHORTENED STATUTORY PERIOD FOR REPL WHICHEVER IS LONGER, FROM THE MAILING D - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period - Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailin earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be tir will apply and will expire SIX (6) MONTHS from a, cause the application to become ABANDONE	N. nely filed the mailing date of this communication. D (35 U.S.C. § 133).			
Status	· (1)				
1) Responsive to communication(s) filed on 4-20	<u>-2007</u> .				
2a) This action is FINAL . 2b) ⊠ This	s action is non-final.				
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is					
closed in accordance with the practice under the	Ex parte Quayle, 1935 C.D. 11, 4	53 O.G. 213.			
Disposition of Claims					
4) Claim(s) 1-20 is/are pending in the application					
4a) Of the above claim(s) 10-20 is/are withdraw	wn from consideration.				
5) Claim(s) is/are allowed.					
6)⊠ Claim(s) <u>1-9</u> is/are rejected.		•			
7) Claim(s) is/are objected to.					
8) Claim(s) are subject to restriction and/o	or election requirement.	•			
Application Papers					
9) ☐ The specification is objected to by the Examine	er.				
10) The drawing(s) filed on is/are: a) accepted or b) objected to by the Examiner.					
Applicant may not request that any objection to the	drawing(s) be held in abeyance. See	e 37 CFR 1.85(a).			
Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Ex		• • • • • • • • • • • • • • • • • • • •			
	kariliner. Note the attached Office	Action of form PTO-192.			
Priority under 35 U.S.C. § 119	•				
12) Acknowledgment is made of a claim for foreign	priority under 35 U.S.C. § 119(a))-(d) or (f).			
a) ☐ All b) ☐ Some * c) ☐ None of:					
1. Certified copies of the priority documents have been received.2. Certified copies of the priority documents have been received in Application No					
2. Certified copies of the priority document3. Copies of the certified copies of the priority	• •				
application from the International Burea	-	ed in this National Stage			
* See the attached detailed Office action for a list		ed.			
	,				
Attachment(s)		•			
1) Notice of References Cited (PTO-892)	4) Interview Summary	(PTO-413)			
2) Notice of Draftsperson's Patent Drawing Review (PTO-948)	Paper No(s)/Mail D	ate			
Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date	5) Notice of Informal F 6) Other:	ratent Application			

Art Unit: 3742

DETAILED ACTION

Claim Rejections - 35 USC § 102

form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

Page 2

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that

(e) the invention was described in (1) an application for patent, published under section 122(b), by

another filed in the United States before the invention by the applicant for patent or (2) a patent

granted on an application for patent by another filed in the United States before the invention by the

applicant for patent, except that an international application filed under the treaty defined in section

351(a) shall have the effects for purposes of this subsection of an application filed in the United States

only if the international application designated the United States and was published under Article 21 (2)

of such treaty in the English language.

2. Claims 1-2 and 5 are rejected under 35 U.S.C. 102(e) as being

Art Unit: 3742

anticipated by Manginell et al (6,527,835).

Manginell teaches a microheater for microanalytical system comprising a microchannel

16 formed on a silicon substrate-wafer 11 and having a length, and a conductor 13 formed in the microchannel 16, the conductor is formed from platinum metal (col.

3,

lines 20-67) and disposed along a majority of the length of the channel 16.

Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
- (a) A patent may not be obtained though the invention is not identically disclosed or described as set

forth in section 102 of this title, if the differences between the subject matter sought to be patented and

the prior art are such that the subject matter as a whole would have been obvious at the time the

invention was made to a person having ordinary skill in the art to which said subject matter pertains.

Patentability shall not be negatived by the manner in which the invention was made.

4. Claims 6-7 and 9 are rejected under 35 U.S.C. 103(a) as being unpatentable over Manginell in view of Ferguson (2003/0209534).

Manginell discloses substantially the claimed invention, but does not disclose quartz

and borosilicate glass. Ferguson discloses resistive heating systems with a substrate

202 comprising quartz and borosilicate glass (page 10, [0068]). It would have been

obvious to one having ordinary skill in the art to modify Manginelrs invention to include

the substrate comprising quartz and borosilicate glass as taught by Ferguson in order to

provide a more rigid structure for the microheater.

As for claim 9, it would have been obvious to include a glass-insulating layer disposed on the conductor 13 because it is conventional to insulate the heaterconductor to avoid short circuitry.

Claims 14-15 and 18-20 are rejected under 35 U.S.C. 103(a) as being unpatentable over Manginell in view of Lin (5,855,801).

Manginell discloses substantially the claimed invention, but does not disclose a method

of fabricating including patterning and etching the substrate.

Lin discloses a method of fabricating a microstructure of a microheater comprising

Art Unit: 3742

microchannel 78 formed on a silicon substrate-wafer 46 including patterning and etching

of the substrate 46 (col. 4, lines 21-67, col. 10, line 53-67) and etching of the substrate

46 with a boron-doped region 52 (col. 4, lines 6-67).

It would have been obvious to one having ordinary skill in the art to modify Manginell's

invention to use a method of fabricating a microstructure including patterning and etching the substrate as taught by Lin as one of the conventional methods of fabricating

a microstructure of the microheater (col. 4, lines 40-45).

*** Page 5 ***************************

Application/Control Number: 10/735,989

Art Unit: 3742

Page 4

etching the substrate as taught by Lin as one of the conventional methods of fabricating

a microstructure of the microheater (col. 4, lines 40-45).

Art Unit: 3742

6. Claim 3 is rejected under 35 U.S.C. 103(a) as being unpatentable over Manginell

in view of Kenny (6,551,849).

Manginell discloses substantially the claimed invention, but does not disclose the conductor comprising aluminum alloy and silicon.

Kenny discloses a method of fabricating arrays of microneedles-microchannels comprising electrically conductive pads 250 comprising aluminum, copper and polysilicon (col. 3, lines 15-25, col. 9, lines 15-25).

The limitation of the conductor comprising an aluminum alloy with 99% aluminum and

silicon and copper, it is deemed that the material used for conductor would be chosen

by the user in order to assure a good conductivity. Therefore it would have been obvious to make the conductor of Manginell out of 99% aluminum, silicon and copper as

taught by Kenny in order to obtain the good conductivity of the microheater (col. 3, lines

15-25, col. 9, lines 15-25).

7. Claims 4 and 8 are rejected under 35 U.S.C. 103(a) as being unpatentable over

Manginell in view of Yamazaki et al (6,165,876) and further in view Ueno et al (2002/00224662).

Art Unit: 3742

Manginell discloses substantially the claimed invention, but does not disclose a substrate comprising a polished silicon wafer, and the conductor-heater comprising

boron ions. Yamazaki discloses a method of doping a silicon film 203 with boron ion

(col. 15, lines 1-18). Ueno discloses a microfluidic device having a heater 3 with a mirror- polished substrate (page 5, [0094]). It would have been obvious to one having

ordinary skill in the art to modify Manginelrs invention to include a doped substrate with

boron ions as taught by Yamazaki and a polished substrate as taught by Ueno and a

conductor comprising boron ions as taught by Yamazaki in order to improve crystallinity

of the film heater-microheater (Abstract)

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Daniel L. Robinson whose telephone number is 571-272-4788. The examiner can normally be reached on m-f 5:30-2:30.

Art Unit: 3742

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Robin Evans can be reached on 571-272-4777. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

dlr

DAMIEL ROBINSON PRIMARY EXAMINER